FB2033

#### **FEATURES**

- 8-bit transceivers
- Latched, registered or straight through in either A to B or B to A path
- Drives heavily loaded backplanes with equivalent load impedances down to 10Ω.
- High drive 100mA BTL Open Collector drivers on B-port
- Allows incident wave switching in heavily loaded backplane buses
- Reduced BTL voltage swing produces less noise and reduces power consumption

- Built-in precision band-gap reference provides accurate receiver thresholds and improved noise immunity
- Compatible with IEEE Futurebus+ or proprietary BTL backplanes
- Each BTL driver has a dedicated Bus GND for a signal return
- Controlled output ramp and multiple GND pins minimize ground bounce
- Glitch-free power up/power down operation
- Low I<sub>CC</sub> current
- Tight output skew
- Supports live insertion

#### **QUICK REFERENCE DATA**

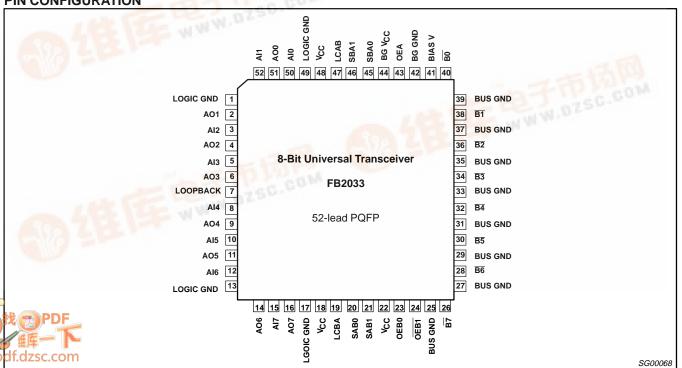
SYMBOL	PA	RAMETER	TYPICAL	UNIT	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay Aln to Bn	A34V	3.0 3.0	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay Bn to AOn	五面 6 = -	4.3 4.1	ns	
C <sub>OB</sub>	Output capacitance (B0 -	Bn only)	6	pF	
l <sub>OL</sub>	Output current (B0 - Bn	only)	100	mA	
48	M.M.M.	Aln to Bn (outputs Low or High)	24		
Icc	Supply current	Bn to AOn (outputs Low)	45	mA	
		Bn to AOn (outputs High)		FeG	

#### ORDERING INFORMATION

PACKAGES	COMMERCIAL RANGE V <sub>CC</sub> = 5V±10%; T <sub>amb</sub> = 0°C to +70°C	DRAWING NUMBER
52-pin Plastic Quad Flat Pack (QFP)	FB2033BB	SOT379-1

NOTE: Thermal mounting or forced air is recommended

#### **PIN CONFIGURATION**



Philips Semiconductors Product specification

# 8-bit latched/registered/pass-thru Futurebus+ universal interface transceiver

FB2033

#### **DESCRIPTION**

The FB2033 is an 8-bit transceiver featuring a split input (AI) and output (AO) bus on the TTL-level side.

The common I/O, open collector B port operates at BTL signal levels. The logic element for data flow in each direction is controlled by two pairs of mode select inputs (SBA0 and SBA1 for B-to-A, SAB0 and SAB1 for A-to-B). It can be configured as a buffer, a register, or a D-type latch.

When configured in the buffer mode, the inverse of the input data appears at the output port. In the flip-flop mode, data is stored on the rising edge of the appropriate clock input (LCAB or LCBA). In the latch mode, clock pins serve as transparent-High latch enables. Regardless of the mode, data is inverted from input to output.

Data flow in the B-to-A direction, regardless of the logic element selected, is further controlled by the Loopback input. When the Loopback input is High the output of the selected A-to-B logic element (not inverted) becomes the B-to-A input.

The 3-State AO port is enabled by asserting a High level on OEA. The B port has two output enables, OEB0 and OEB1. Only when OEB0 is High and OEB1 is Low is the output enabled. When either OEB0 is Low or OEB1 is High, the B-port is inactive and is pulled to the level of the pull-up voltage. New data can be entered in the flip-flop and latched modes or can be retained while the associated outputs are in 3-State (AO port) or inactive (B port).

The B-port drivers are Low-capacitance open collectors with controlled ramp and are designed to sink 100mA. Precision band gap references on the B-port ensure very good noise margins by limiting the switching threshold to a narrow region centered at 1.55V.

The B-port interfaces to "Backplane Transceiver Logic" (see the IEEE 1194.1 BTL standard). BTL features low power consumption

by reducing voltage swing (1V p-p, between 1V and 2V) and reduced capacitive loading by placing an internal series diode on the drivers. BTL also provides incident wave switching, a necessity for high performance backplanes.

Output clamps are provided on the BTL outputs to further reduce switching noise. The " $V_{OH}$ " clamp reduces inductive ringing effects during a Low-to-High transition. The " $V_{OH}$ " clamp is always active. The other clamp, the "trapped reflection" clamp, clamps out ringing below the BTL 0.5V  $V_{OL}$  level. This clamp remains active for approximately 100ns after a High-to-Low transition.

To support live insertion, OEB0 is held Low during power on/off cycles to ensure glitch- free B port drivers. Proper bias for B port drivers during live insertion is provided by the BIAS V pin when at a 5V level while  $V_{CC}$  is Low. The BIAS V pin is a low current input which will reverse-bias the BTL driver series Schottky diode, and also bias the B port output pins to a voltage between 1.62V and 2.1V. This bias function is in accordance with IEEE BTL Standard 1194.1. If live insertion is not a requirement, the BIAS V pin should be tied to a  $V_{CC}$  pin.

The LOGIC GND and BUS GND pins are isolated inside the package to minimize noise coupling between the BTL and TTL sides. These pins should be tied to a common ground external to the package.

Each BTL driver has an associated BUS GND pin that acts as a signal return path and these BUS GND pins are internally isolated from each other. In the event of a ground return fault, a "hard" signal failure occurs instead of a pattern dependent error that may be very infrequent and impossible to trouble- shoot.

As with any high power device thermal considerations are critical. It is recommended that airflow (300lfpm) and/or thermal mounting be used to ensure proper junction temperature.

#### PIN DESCRIPTION

THE DESCRIPTION							
SYMBOL	PIN NUMBER	TYPE	NAME AND FUNCTION				
AI0 – AI7	50, 52, 3, 5, 8, 10, 12, 15	Input	Data inputs (TTL)				
AO0 – AO7	51, 2, 4, 6, 9, 11, 14, 16	Output	3-State outputs (TTL)				
B0 – B7	40, 38, 36, 34, 32, 30, 28, 26	I/O	Data inputs/Open Collector outputs, High current drive (BTL)				
OEB0	23	Input	Enables the B outputs when High				
OEB1	24	Input	Enables the B outputs when Low				
OEA	43	Input	Enables the AO outputs when High				
BUS GND	39, 37, 35, 33, 31, 29, 27, 25	GND	Bus ground (0V)				
LOGIC GND	1, 13, 17, 49	GND	Logic ground (0V)				
V <sub>CC</sub>	18, 22, 48	Power	Positive supply voltage				
BIAS V	41	Power	Live insertion pre-bias pin				
BG V <sub>CC</sub>	44	Power	Band Gap threshold voltage reference				
BG GND	42	GND	Band Gap threshold voltage reference ground				
SABn	20, 21	Input	Mode select from AI to B				
SBAn	45, 46	Input	Mode select from B to AO				
LCAB	47	Input	A-to-B clock/latch enable (transparent latch when High)				
LCBA	19	Input	B-to-A clock/latch enable (transparent latch when High)				
Loopback	7	Input	Enables loopback function when High (from Aln to AOn)				

FB2033

#### **FUNCTION TABLE**

					INPUTS	3				ОИТІ	OUTPUTS	
MODE	Aln	Bn*	OEB0	OEB1	OEA	LCAB	LCBA	SAB <sub>1</sub>	SBA <sub>1</sub>	AOn	Bn	
Aln to Bn thru mode	L	_	Н	L	L	Х	Х	LL	XX	Z	H**	
Ain to bit tilla mode	Н	_	Н	L	L	Х	Х	LL	XX	Z	L	
Ale to De transport lately	L	_	Н	L	L	Н	Х	НХ	XX	Z	H**	
Aln to Bn transparent latch	Н	_	Н	L	L	Н	Х	НХ	XX	Z	L	
Aln to Bn latch and read	Ι	_	Н	L	L	$\downarrow$	Х	HX	XX	Z	H**	
All to bil latell and read	h	_	Н	L	L	$\downarrow$	Х	НХ	XX	Z	L	
Aln to Bn register	L	_	Н	L	L	1	Х	LH	XX	Z	H**	
All to billegister	Н	_	Н	L	L	1	Х	LH	XX	Z	L	
Bn outputs latched and read (preconditioned latch)	Х	_	н	L	L	L	х	НХ	xx	Z	latched data	
Bn to AOn thru mode	Х	L	L	Н	Н	Х	Х	XX	LL	Н	input	
Bit to AOII tilla filode	Х	Н	L	Н	Н	Х	Х	XX	LL	L	input	
Bn to AOn transparent latch	Х	L	L	Н	Н	Х	Н	XX	HX	Н	input	
Bit to AOII transparent lateri	Х	Н	L	Н	Н	Х	Н	XX	HX	L	input	
Bn to AOn latch and read	Х	ı	L	Н	Н	Х	$\downarrow$	XX	HX	Н	input	
Bit to AOIT later and read	Х	h	L	Н	Н	Х	$\downarrow$	XX	HX	L	input	
Bn to AOn register	Х	L	L	Н	Н	Х	1	XX	LH	Н	input	
Bit to AOT register	Х	Н	L	Н	Н	Х	1	XX	LH	L	input	
AOn outputs latched and read (preconditioned latch)	Х	Х	L	Н	Н	Х	L	XX	НХ	latched data	Х	
Disable Bn outputs	Х	Х	L	Х	Х	Х	Х	XX	XX	Х	H**	
Disable bil outputs	Х	Х	Х	Н	Х	Х	Х	XX	XX	Х	H**	
Disable AOn outputs	Х	Х	Х	Х	L	Х	Х	XX	XX	Z	Х	

#### **FUNCTION SELECT TABLE**

MODE SELECTED	SXX1	SXX0
Thru mode	L	L
Register mode	L	Н
Latch mode	Н	Х

### NOTES:

H = High voltage level

L = Low voltage level

h = High voltage level one set-up time prior to the High-to-Low LCXX transition

I = Low voltage level one set-up time prior to the High-to-Low LCXX transition

X = Don't care

Z = High-impedance (OFF) state

— = Input not externally driven

↑ = Low-to-High transition

↓ = High-to-Low transition

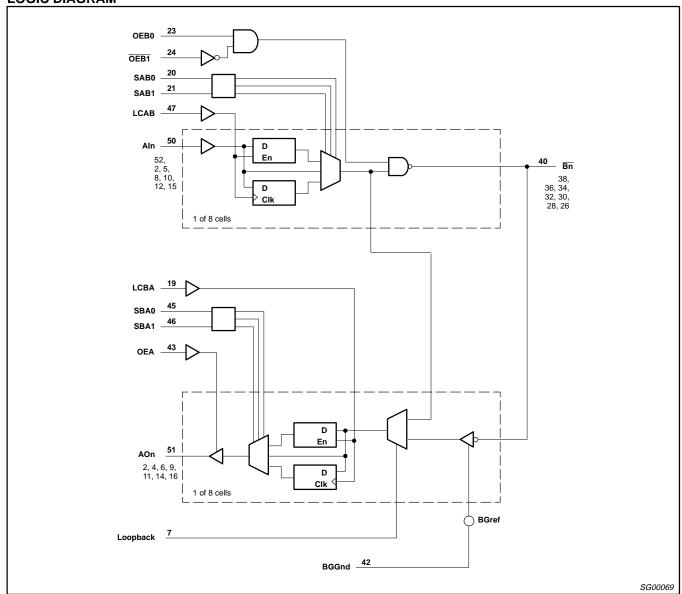
H\*\* = Goes to level of pull-up voltage

Bn\* = Precaution should be taken to ensure B inputs do not float. If they do, they are equal to Low state.

NOTE: In Loopback mode (Loopback = High), Aln inputs are routed to the AOn outputs. The Bn inputs are blocked out.

FB2033

## **LOGIC DIAGRAM**



Philips Semiconductors Product specification

# 8-bit latched/registered/pass-thru Futurebus+ universal interface transceiver

FB2033

ABSOLUTE MAXIMUM RATINGS
Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.

SYMBOL	PARAMETER		RATING	UNIT	
V <sub>CC</sub>	Supply voltage	-0.5 to +7.0	V		
V	Input voltage	All inputs except BO – Bn	-1.2 to +7.0	V	
V <sub>IN</sub>	Input voltage	B0 – Bn	-1.2 to +3.5		
I <sub>IN</sub>	Input current	-40 to +5.0	mA		
V <sub>OUT</sub>	Voltage applied to output in High output state		-0.5 to +V <sub>CC</sub>	V	
	Current applied to output in Low output state	AO0 – AOn	48	A	
Гоит	Current applied to output in Low output state	B0 – Bn	200	mA	
T <sub>STG</sub>	Storage temperature	-65 to +150	°C		

### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	DADAMETER			LIMITS		UNIT
STWIBUL	PARAMETER	TAKAMETEK			MAX	UNII
V <sub>CC</sub>	Supply voltage		4.5	5.0	5.5	V
V	High level input voltage	Except BO – Bn	2.0			V
$V_{IH}$	High-level input voltage	BO – Bn	1.62	1.55		V
V	Low-level input voltage	Except BO – Bn			0.8	V
$V_{IL}$		BO – Bn			1.47	1 '
	Input clamp current	Except B0 – Bn			-40	mA
lık		BO – Bn			-50	
Гон	High-level output current	AO0 – AOn			-3	mA
	l and land and and an entered	AO0 – AOn			24	A
l <sub>OL</sub>	Low-level output current	BO – Bn			100	mA
I <sub>IA</sub>	Off device input current	Except $\overline{B0} - \overline{Bn}$ , V <sub>I</sub> = 0 to 5.5V, V <sub>CC</sub> = 0V			100	μΑ
C <sub>OB</sub>	Output capacitance of B port			6	7	pF
T <sub>amb</sub>	Operating free-air temperature range		0		+70	°C

Philips Semiconductors Product specification

# 8-bit latched/registered/pass-thru Futurebus+ universal interface transceiver

FB2033

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating free-air temperature range unless otherwise noted.

CVMDOL	PARAMETER		TEST CONDITIONS		UNIT			
SYMBOL	PARAMETE	K	TEST CONDITIONS <sup>1</sup>	MIN	TYP <sup>2</sup>	MAX	UNII	
I <sub>OH</sub>	High level output current	B0 – Bn	$V_{CC} = MAX$ , $V_{IL} = MAX$ , $V_{IH} = MIN$ , $V_{OH} = 1.9V$			100	μА	
I <sub>OFF</sub>	Power-off output current	B0 – Bn	$V_{CC} = 0.0V$ , $V_{IL} = MAX$ , $V_{IH} = MIN$ , $V_{OH} = 1.9V$			100	μΑ	
V <sub>OH</sub>	High-level output voltage	AO0 – AOn <sup>4</sup>	$V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN, I_{OH} = -3mA$	2.5	2.85		V	
		AO0 – AOn <sup>4</sup>	$V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN, I_{OL} = 24mA$			0.5		
$V_{OL}$	Low-level output voltage	B0 – Bn	$V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN, I_{OL} = 100mA$	.75	1.0	1.15	V	
		B0 - B11	$V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN, I_{OL} = 4mA$	0.5				
		Except B0-Bn	$V_{CC} = MIN, I_I = I_{IK}$			-0.5		
$V_{IK}$	Input clamp voltage	B0 – Bn	$V_{CC} = MIN, I_I = I_{IK}^{6}$	0.3			V	
		B0 - B11	V <sub>CC</sub> = MIN, I <sub>I</sub> = -18mA			-1.2		
I <sub>I</sub>	Input current at maximum input voltage	Except B0-Bn	$V_{CC} = MAX$ , $V_I = 0.0V$ or 5.5V			±50	μΑ	
		Except B0-Bn	$V_{CC} = MAX, V_I = 2.7V, \overline{Bn} = Aln = 0V$			20	μА	
I <sub>IH</sub>	High-level input current	B0 – Bn	V <sub>CC</sub> = MAX, V <sub>I</sub> = 1.9V			100		
		BU - BII	V <sub>CC</sub> = MAX, V <sub>I</sub> = 3.5V <sup>5</sup>	100			mA	
اړر	Low-level input current	Except B0-Bn	V <sub>CC</sub> = MAX, V <sub>I</sub> = 0.5V			-20	μА	
,,,	· '	BO – Bn	V <sub>CC</sub> = MAX, V <sub>I</sub> = 0.75V			-100	] `	
lozh	Off-state output current	AO0 – AOn	$V_{CC} = MAX, V_O = 2.7V$			50	μА	
I <sub>OZL</sub>	Off-state output current	AO0 – AOn	$V_{CC} = MAX, V_O = 0.5V$			-50	μА	
los	Short-circuit output current <sup>3</sup>	AO0 – AOn only	$V_{CC} = MAX, V_O = 0.0V$	-45		-150	mA	
		Aln to Bn	V <sub>CC</sub> = MAX, outputs Low or High		24	50		
Icc	Supply current (total)	Bn to AOn	V <sub>CC</sub> = MAX, outputs Low		45	75	mA	
		Bn to AOn	V <sub>CC</sub> = MAX, outputs High		22	44		

- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operation conditions for the applicable type.
   All typical values are at V<sub>CC</sub> = 5V, T<sub>amb</sub> = 25°C.
   Not more than one output should be shorted at a time. For testing I<sub>OS</sub>, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order internal heating and more accurately reflect operational values. Otherwise, prolonged shorting the latter than the property of the of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.
   Due to test equipment limitations, actual test conditions are V<sub>IH</sub> = 1.8V and V<sub>IL</sub> = 1.3V for the B side.
   For B port input voltage between 3 and 5 volts I<sub>IH</sub> will be greater than 100μA, but the parts will continue to function normally.
   BO – B7 clamps remain active for a minimum of 80ns following a High-to-Low transition.

FB2033

#### LIVE INSERTION SPECIFICATIONS

CVMDOL		DADAMETED		LIMITS			
SYMBOL		PARAMETER	MIN	NOM	MAX	UNIT	
V <sub>BIASV</sub>	Bias pin voltage	$V_{CC} = 0$ to 5.25V, $\overline{Bn} = 0$ to 2.0V	4.5		5.5	V	
	Diag nin DC gurrant	$V_{CC} = 0$ to 4.75V, $\overline{Bn} = 0$ to 2.0V, Bias V = 4.5 to 5.5V			1	mA	
I <sub>BIASV</sub>	Bias pin DC current	$V_{CC} = 4.5 \text{ to } 5.5 \text{V}, \overline{Bn} = 0 \text{ to } 2.0 \text{V},$ Bias V = 4.5 to 5.5 V			10	μΑ	
V <sub>Bn</sub>	Bus voltage during pre-bias	$\overline{B0} - \overline{B8} = 0$ V, Bias V = 5.0V	1.62		2.1	V	
I <sub>LM</sub>	Fall current during pre-bias	$\overline{B0} - \overline{B8} = 2V$ , Bias V = 4.5 to 5.5V	1			μΑ	
I <sub>HM</sub>	Rise current during pre-bias	$\overline{B0} - \overline{B8} = 1V$ , Bias V = 4.5 to 5.5V	-1			μΑ	
I <sub>Bn</sub> PEAK	Peak bus current during insertion	$V_{CC} = 0$ to 5.25V, $\overline{B0} - \overline{B8} = 0$ to 2.0V, Bias V = 4.5 to 5.5V, OEB0 = 0.8V, $t_r = 2$ ns			10	mA	
I <sub>OI</sub> OFF	Dower up ourrent	$V_{CC} = 0$ to 5.25V, OEB0 = 0.8V			100		
IOLUFF	Power up current	$V_{CC} = 0$ to 2.2V, OEB0 = 0 to 5V			100	μΑ	
t <sub>GR</sub>	Input glitch rejection	V <sub>CC</sub> = 5.0V	1.0	1.35		ns	

#### **AC ELECTRICAL CHARACTERISTICS**

			A PORT LIMITS					
SYMBOL	PARAMETER	TEST CONDITION	T <sub>amb</sub> = C <sub>L</sub> = 5	+25°C, V <sub>(</sub> 50pF, R <sub>L</sub> =	<sub>CC</sub> = 5V, = <b>500</b> Ω	$T_{amb} = 0$ $V_{CC} = 5$ $C_{L} = 50pF,$	UNIT	
			MIN	TYP	MAX	MIN	MAX	
f <sub>MAX</sub>	Maximum clock frequency	Waveform 4	100	150		100		MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (thru mode) Bn to AOn	Waveform 1, 2	2.2 2.0	4.3 4.1	6.0 6.0	2.0 1.8	7.0 7.0	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (transparent latch) Bn to AOn	Waveform 1, 2	1.5 2.4	4.5 4.4	6.5 6.5	1.0 2.0	7.5 7.5	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay LCBA to AOn	Waveform 1, 2	2.0 2.2	3.8 4.3	5.5 6.0	1.8 1.7	6.0 6.5	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay SBAn to AOn	Waveform 1, 2	1.4 1.4	2.9 3.1	5.0 5.5	1.0 1.0	6.0 6.5	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (Loopback mode) Aln to AOn	Waveform 1, 2	2.0 2.0	3.8 3.9	6.0 6.0	2.8 2.3	7.0 7.0	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (Loopback mode) Loopback to AOn	Waveform 1, 2	1.2 1.2	3.4 3.2	5.0 5.5	1.0 1.0	6.0 6.5	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time from High or Low OEA to AOn	Waveform 5, 6	1.0 2.6	3.1 4.0	5.1 5.5	1.0 2.4	5.5 5.8	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time to High or Low OEA to AOn	Waveform 5, 6	1.0 1.0	3.5 3.3	5.0 4.6	1.7 1.7	5.6 5.2	ns
t <sub>TLH</sub> t <sub>THL</sub>	Output transition time, AOn Port 10% to 90%, 90% to 10%	Test Circuit and Waveforms				2.0 2.0	5.0 5.0	ns
t <sub>SK</sub> (o)	Output to output skew, A port <sup>1</sup>	Waveform 3		0.5	1.0		1.5	ns
t <sub>SK</sub> (p)	Pulse skew 2  t <sub>PHL</sub> - t <sub>PLH</sub>   <sub>MAX</sub>	Waveform 2		0.3	1.0		1.5	ns

#### NOTES:

- 1. Bn to AOn propagation delays are extended for 5 nanoseconds following B port excursions above 3.1 volts.
- It by Actual to Actual I for any data input to output path compared to any other data input to output path where N and M are either LH or HL. Skew times are valid only under same test conditions (temperature, V<sub>CC</sub>, loading, etc.).
   t<sub>SK</sub>(p) is used to quantify duty cycle characteristics. In essence it compares the input signal duty cycle to the corresponding output signal duty cycle (50MHz input frequency and 50% duty cycle, tested on data paths only).

Philips Semiconductors Product specification

# 8-bit latched/registered/pass-thru Futurebus+ universal interface transceiver

FB2033

#### AC ELECTRICAL CHARACTERISTICS (Continued)

	PARAMETER		B PORT LIMITS					
SYMBOL		TEST CONDITION	$T_{amb}$ = +25°C, $V_{CC}$ = 5V, $C_D$ = 30pF, $R_U$ = $9\Omega$			T <sub>amb</sub> = 0 V <sub>CC</sub> = 5 C <sub>D</sub> = 30pl	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (thru mode) Aln to Bn	Waveform 1, 2	1.2 1.0	2.9 2.9	4.3 4.4	1.0 1.0	4.8 4.6	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (transparent latch) Aln to Bn	Waveform 1, 2	1.4 1.0	3.1 3.3	4.5 4.8	1.0 1.0	5.1 5.1	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay LCAB to Bn	Waveform 1, 2	2.7 2.2	4.4 5.1	5.7 6.6	2.4 2.0	6.4 7.1	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay SABn to Bn	Waveform 1, 2	1.8 1.0	3.6 3.3	5.0 4.9	1.4 1.0	5.7 5.2	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Enable/disable time OEB0 or OEB1 to Bn	Waveform 1, 2	1.4 1.0	3.0 3.1	4.5 5.0	1.0 1.0	5.0 5.6	ns
ΔV/Δt	Output transition rate, Bn Port 20% to 80%, 80% to 20%	Test Circuit and Waveforms				0.4	1.2	V/ns
t <sub>SK</sub> (o)	Output to output skew, B port <sup>1</sup>	Waveform 3		0.8	1.5		2.0	ns
t <sub>SK</sub> (p)	Pulse skew 2  t <sub>PHL</sub> - t <sub>PLH</sub>   <sub>MAX</sub>	Waveform 2		0.3	1.5			ns
SYMBOL	PARAMETER	TEST CONDITION	F	R <sub>U</sub> = 16.59	Ω	$R_U = 16.5\Omega$		UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (thru mode) Aln to Bn	Waveform 1, 2	1.2 1.0	3.0 3.0	4.4 4.5	1.0 1.0	4.9 4.7	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay (transparent latch) Aln to Bn	Waveform 1, 2	1.4 1.0	3.2 3.4	4.6 4.9	1.0 1.0	5.2 5.2	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay LCAB to Bn	Waveform 1, 2	2.7 2.2	4.5 5.2	5.8 6.7	2.4 2.0	6.5 7.2	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay SABn to Bn	Waveform 1, 2	1.8 1.0	3.7 3.4	5.1 5.0	1.4 1.0	5.8 5.3	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Enable/disable time OEB0 or OEB1 to Bn	Waveform 1, 2	1.4 1.0	3.1 3.2	4.6 5.1	1.0 1.0	5.1 5.7	ns
ΔV/Δt	Output transition rate, Bn Port 20% to 80%, 80% to 20%	Test Circuit and Waveforms				0.2	0.6	V/ns
t <sub>SK</sub> (o)	Output to output skew, B port <sup>1</sup>	Waveform 3		0.5	1.0		1.5	ns
t <sub>SK</sub> (p)	Pulse skew <sup>2</sup>  t <sub>PHL</sub> - t <sub>PLH</sub>   <sub>MAX</sub>	Waveform 2		0.3	1.0		1.5	ns

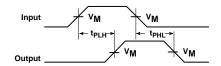
It<sub>PN</sub>actual – t<sub>PM</sub>actual | for any data input to output path compared to any other data input to output path where N and M are either LH or HL. Skew times are valid only under same test conditions (temperature, V<sub>CC</sub>, loading, etc.).
 t<sub>SK</sub>(p) is used to quantify duty cycle characteristics. In essence it compares the input signal duty cycle to the corresponding output signal duty cycle (50MHz input frequency and 50% duty cycle, tested on data paths only).

FB2033

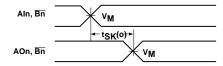
#### **AC SETUP REQUIREMENTS**

					LIMI'	TS		
SYMBOL	PARAMETER	TEST	T <sub>amb</sub> =	+25°C, V	<sub>CC</sub> = 5V	T <sub>amb</sub> = 0 to 70°C, V <sub>CC</sub> = 5V±10%		UNIT
STWIBOL		CONDITION				C <sub>D</sub> = 30pF (E R <sub>U</sub> = 9Ω (B		ONII
			MIN	TYP	MAX	MIN	MAX	
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup time Aln to LCAB or Bn to LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time Aln to LCAB or Bn to LCBA	Waveform 4	1.0 1.0			1.3 1.3		ns
t <sub>w</sub> (H) t <sub>w</sub> (L)	Pulse width, High or Low LCAB or LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns
SYMBOL	PARAMETER	TEST CONDITION				C <sub>D</sub> = 30pF (E R <sub>U</sub> = 16.5Ω (		UNIT
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup time Aln to LCAB or Bn to LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time Aln to LCAB or Bn to LCBA	Waveform 4	1.0 1.0			1.3 1.3		ns
t <sub>w</sub> (H) t <sub>w</sub> (L)	Pulse width, High or Low LCAB or LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns

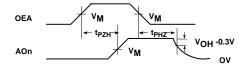
### **AC WAVEFORMS**



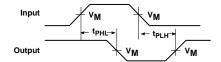
Waveform 1. Propagation Delay for Data or Output Enable to Output



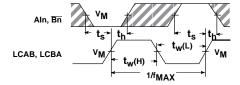
Waveform 3. Output to Output Skew



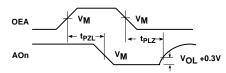
Waveform 5. 3-State Output Enable Time to High Level and Output Disable Time from High Level



Waveform 2. Propagation Delay for Data or Output Enable to Output



Waveform 4. Setup and Hold Times, Pulse Widths and Maximum Frequency



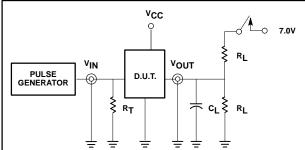
Waveform 6. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

NOTE: The shaded areas indicate when the input is permitted to change for predictable output performance.

SG00070

FB2033

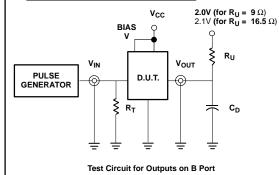
#### **TEST CIRCUIT AND WAVEFORMS**



Test Circuit for 3-State Outputs on A Port

#### **SWITCH POSITION**

TEST	ST SWITCH		
t <sub>PLZ,</sub> t <sub>PZL</sub>	closed		
All other	open		



NEGATIVE PULSE	90% t <sub>W</sub> V <sub>M</sub> 10%	90% AMP (V) 10% LOW V +TLH (t <sub>r</sub> )
POSITIVE PULSE	t <sub>TLH</sub> (t <sub>r</sub> ) 90% V <sub>M</sub> t <sub>W</sub>	90% tTHL (t <sub>f</sub> ) AMP (V)  10% LOW V

 $V_{M} = 1.55V$  for  $\overline{Bn}$ ,  $V_{M} = 1.5V$  for all others. **Input Pulse Definitions** 

Family	INPUT PULSE REQUIREMENTS							
FB+	Amplitude	Low V	Rep. Rate	t <sub>W</sub>	t <sub>TLH</sub>	t <sub>THL</sub>		
A Port	3.0V	0.0V	1MHz	500ns	2.5ns	2.5ns		
B Port	2.0V	1.0V	1MHz	500ns	2.0ns	2.0ns		

#### **DEFINITIONS:**

R<sub>L</sub> = Load Resistor; see AC CHARACTERISTICS for value.

Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

Termination resistance should be equal to Z<sub>OUT</sub> of pulse generators.

Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R<sub>U</sub> = Pull up resistor; see AC CHARACTERISTICS for value.

SG00063